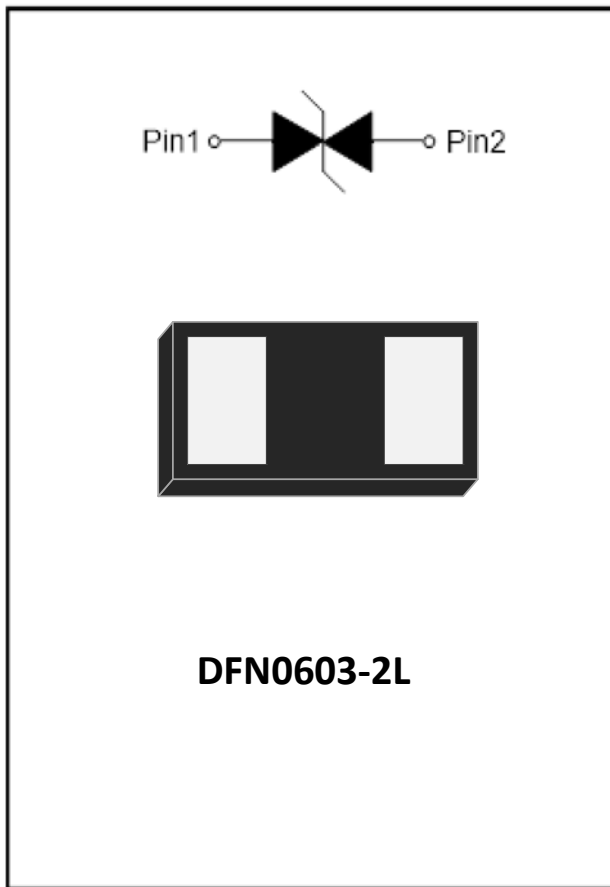


## 1- Line, Bi-directional, Ultra-low Capacitance, Transient Voltage Suppressor



### Features

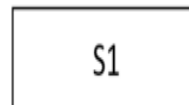
- Stand-off voltage:  $\pm 5V$  Max
- Transient protection for each line according to  
IEC61000-4-2(ESD):  $\pm 15kV$  (contact)  
IEC61000-4-5(surge): 5.5A (8/20 $\mu s$ )
- Low leakage current
- Ultra-low capacitance:  $C_j = 0.3pF$  typ.
- Low clamping voltage:  
 $V_{CL} = 7.5V$  typ. @  $I_{PP} = 16A$  (TLP)
- RoHS Compliant
- Solid-state silicon technology

### Applications

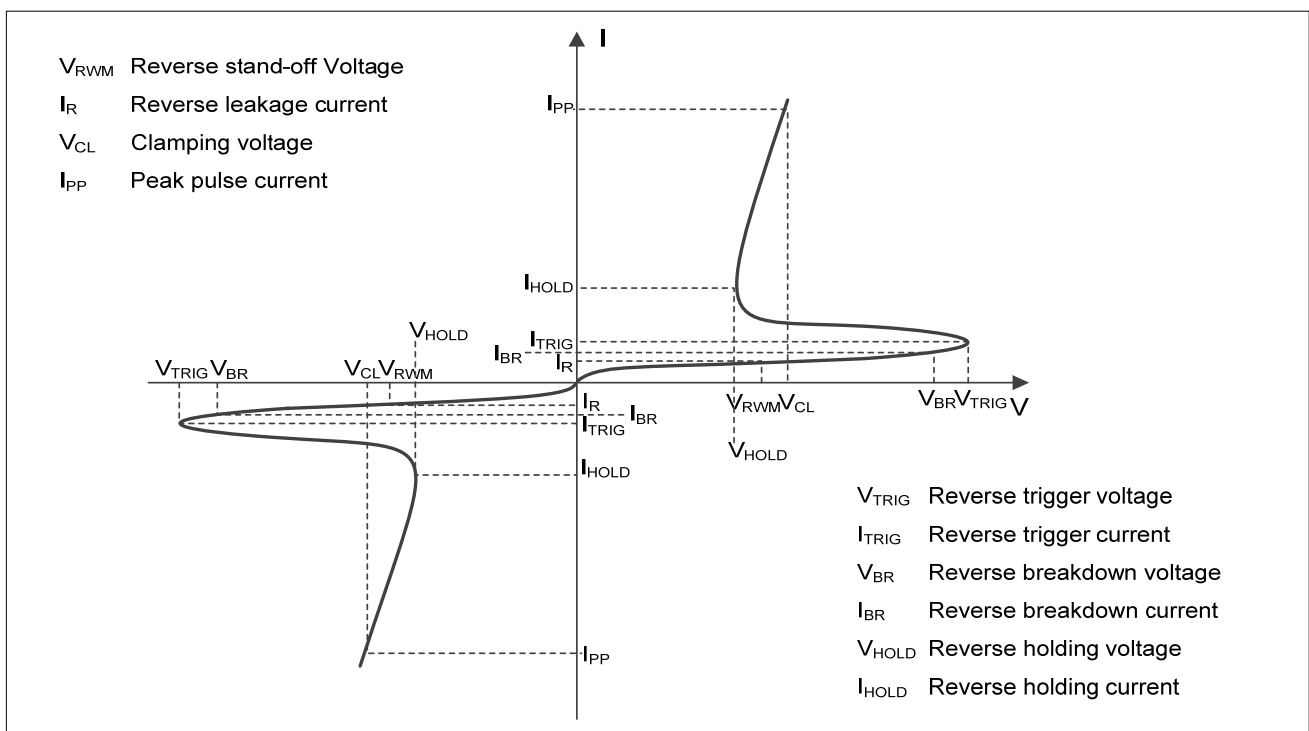
- Cellular handsets
- Tablets
- Laptops
- Other portable devices
- Network communication devices

### Mechanical Data

- Package: DFN0603-2L
- Case Material: "Green" Molding Compound
- Moisture Sensitivity: Level 3 per J-STD-020
- Marking Information: See Below



### ■Definitions of electrical characteristics





# SESDULC5V0LZB

## ■Maximum Ratings

| PARAMETER                                       | SYMBOL    | LIMITS   | UNIT        |
|-------------------------------------------------|-----------|----------|-------------|
| Peak pulse power ( $t_p = 8/20\mu s$ )          | $P_{pk}$  | 33       | W           |
| Peak pulse current ( $t_p = 8/20\mu s$ )        | $I_{PP}$  | 5.5      | A           |
| ESD according to IEC61000-4-2 air discharge     | $V_{ESD}$ | $\pm 30$ | kV          |
| ESD according to IEC61000-4-2 contact discharge |           | $\pm 15$ |             |
| Junction temperature                            | $T_J$     | -40~125  | $^{\circ}C$ |
| Storage temperature                             | $T_{STG}$ | -55~150  | $^{\circ}C$ |

## ■Electrical Characteristics ( $T_a=25^{\circ}C$ Unless otherwise specified)

| PARAMETER                       | Symbol     | UNIT    | Conditions                           | Min | Typ | Max  |
|---------------------------------|------------|---------|--------------------------------------|-----|-----|------|
| Reverse maximum working voltage | $V_{RWM}$  | V       |                                      |     |     | 5    |
| Reverse leakage current         | $I_R$      | $\mu A$ | $V_{RWM} = 5V$                       |     |     | 0.1  |
| Reverse breakdown voltage       | $V_{BR}$   | V       | $I_{BR} = 1mA$                       | 6   |     |      |
| Reverse holding voltage         | $V_{HOLD}$ | V       |                                      | 1.5 |     |      |
| Clamping voltage <sup>1)</sup>  | $V_{CL}$   | V       | $I_{PP} = 16A, t_p = 0.2/100ns(TLP)$ |     | 7.5 |      |
| Clamping voltage <sup>1)</sup>  | $V_{CL}$   | V       | $I_{PP} = 1A, t_p = 8/20\mu s$       |     | 3   | 3.5  |
| Clamping voltage <sup>1)</sup>  | $V_{CL}$   | V       | $I_{PP} = 5.5A, t_p = 8/20\mu s$     |     | 5   | 6    |
| Junction capacitance            | $C_J$      | pF      | $V_R = 0V, f = 1MHz$                 |     |     | 0.22 |

Notes:

TLP parameter:  $Z_0 = 50\Omega$ ,  $t_p = 100ns$ ,  $t_r = 2ns$ , averaging window from 60ns to 80ns. RDYN is calculated from 4A to 16A.

Contact discharge mode, according to IEC61000-4-2.

Non-repetitive current pulse, according to IEC61000-4-5.

## ■Ordering Information (Example)

| PREFERRED P/N | PACKING CODE | UNIT WEIGHT(mg)  | MINIMUM PACKAGE(pcs) | INNER BOX QUANTITY(pcs) | OUTER CARTON QUANTITY(pcs) | DELIVERY MODE |
|---------------|--------------|------------------|----------------------|-------------------------|----------------------------|---------------|
| SESDULC5V0LZB | F1           | Approximate 0.18 | 10000                | 100000                  | 400000                     | 7" reel       |



## ■ Characteristics (Typical)

Fig.1 8/20 $\mu$ s waveform per IEC61000-4-5

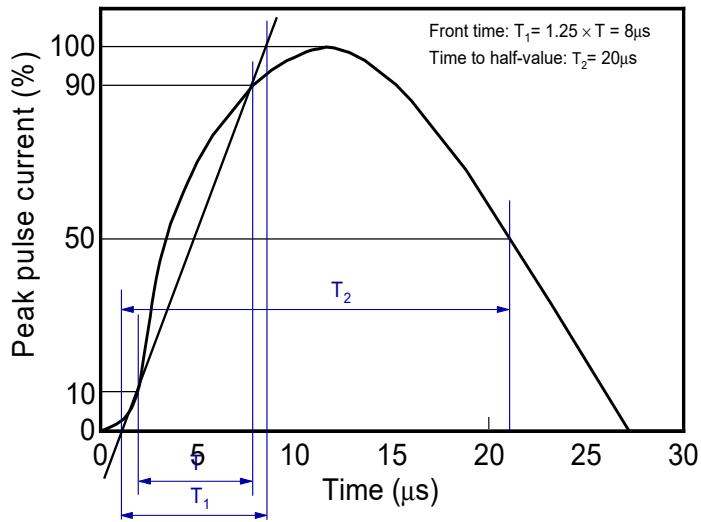


Fig.2 Contact discharge current waveform per IEC61000-4-2

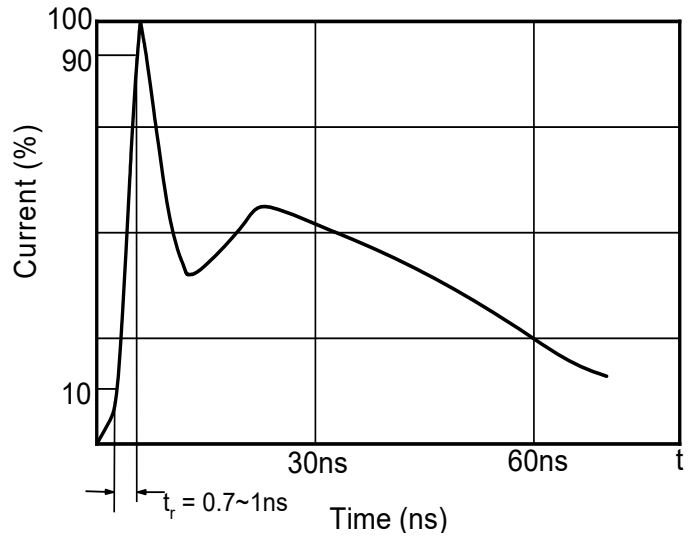


Fig.3 Clamping voltage vs. Peak pulse current

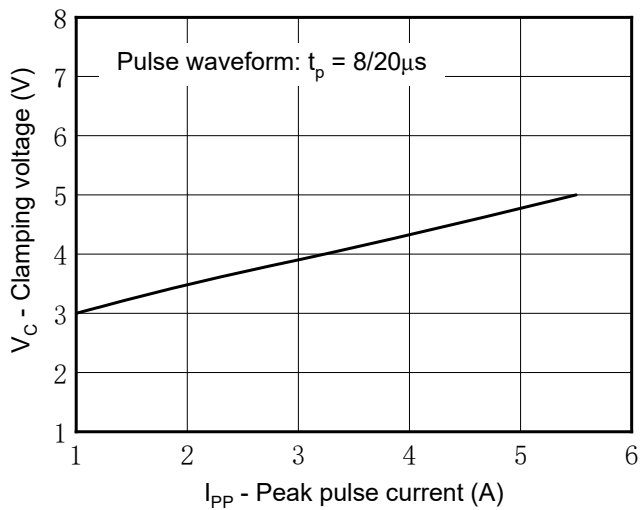


Fig.4 Capacitance vs. Reverse voltage

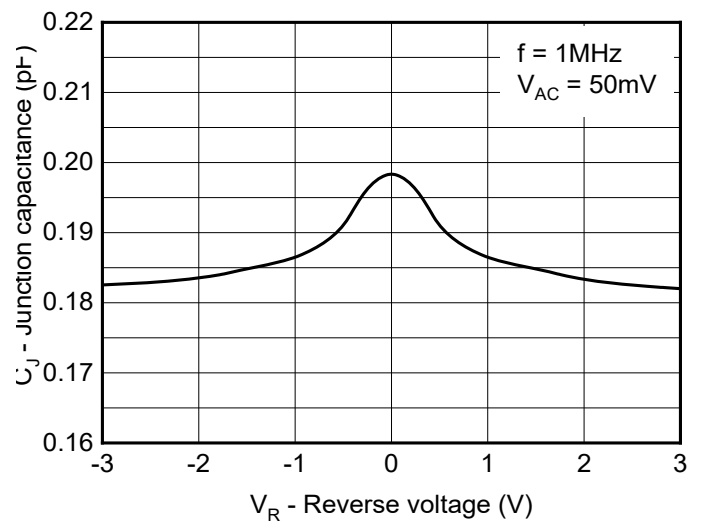


Fig.5 Non-repetitive peak pulse power vs. Pulse time

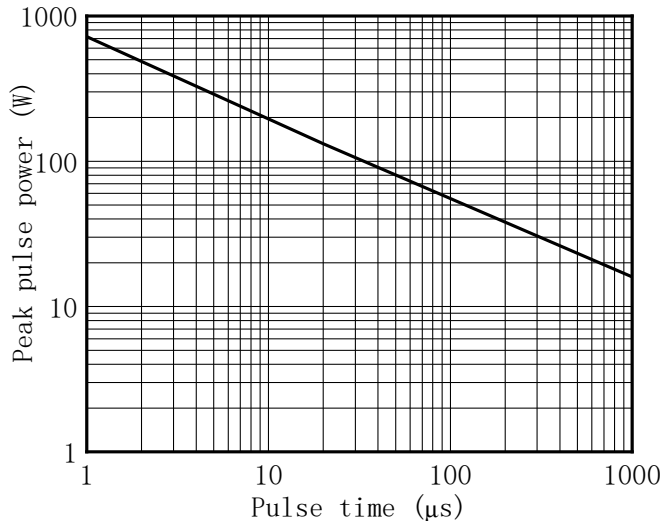


Fig.6 Power derating vs. Ambient temperature

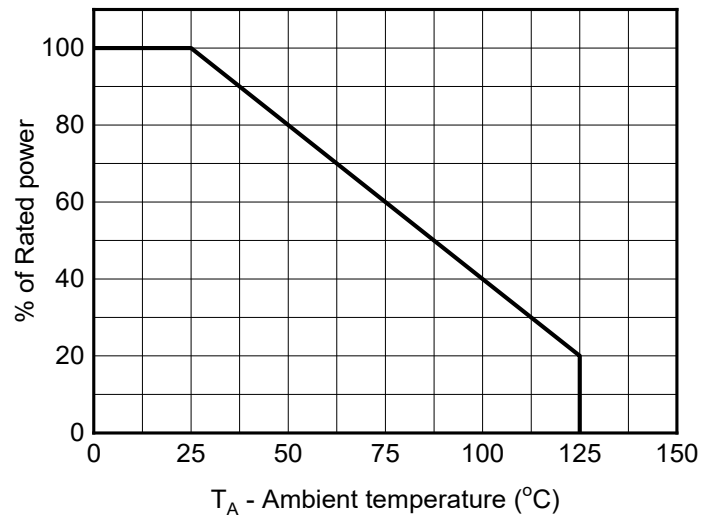
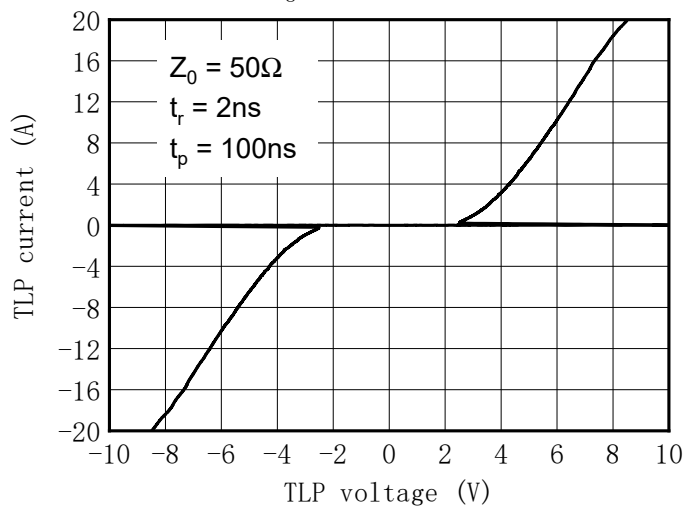




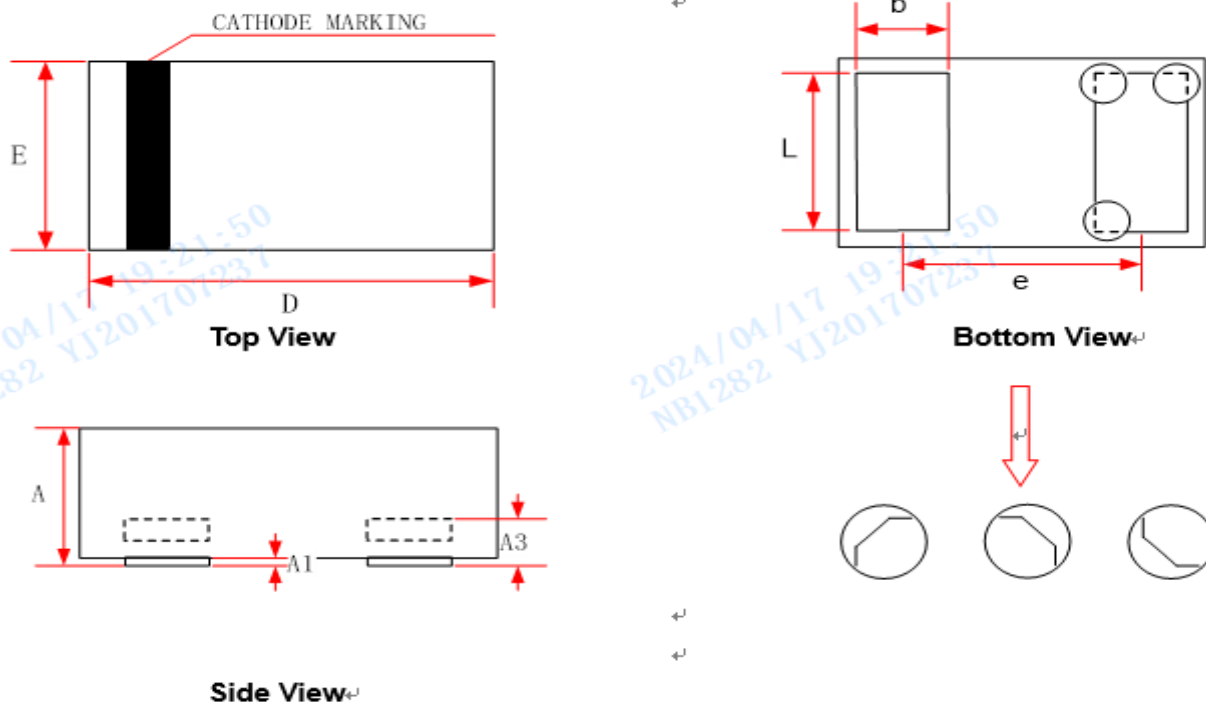
Fig.7 TLP Measurment





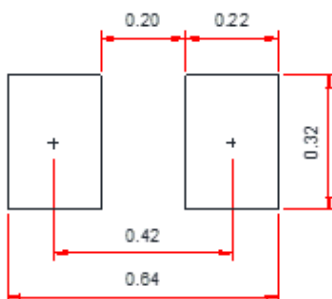
## SESDULC5V0LZB

### ■ Outline Dimensions



| Symbol | Dimensions in Millimeters |       |       |
|--------|---------------------------|-------|-------|
|        | Min.                      | Typ.  | Max.  |
| A      | 0.230                     | 0.300 | 0.350 |
| A1     | 0.000                     | -     | 0.050 |
| A3     | 0.102REF.                 |       |       |
| D      | 0.550                     | 0.600 | 0.670 |
| E      | 0.250                     | 0.300 | 0.370 |
| b      | 0.100                     | 0.170 | 0.250 |
| L      | 0.200                     | 0.240 | 0.280 |
| e      | 0.360 BSC                 |       |       |

### ■ Recommended PCB Layout



Unit:mm

#### Notes:

This recommended land pattern is for reference purposes only. Please consult your manufacturing group to ensure your PCB design guidelines are met



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